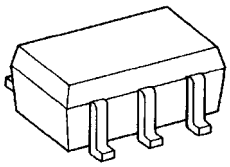
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SG86FU

EXCLUSIVE OR Gate

Features

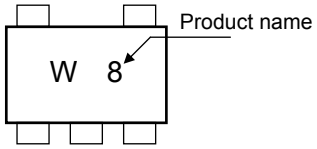
- High-level output current: I_{OH}/I_{OL} = ±8 mA (min) at V_{CC} = 3 V
- High-speed operation: t_{pd} = 2.7 ns (typ.) at V_{CC} = 3.3 V,15pF
- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs.
- 3.6-V power down protection output.



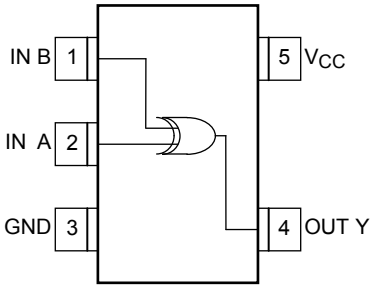
SSOP5-P-0.65A (USV)

Weight: 0.006 g (typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V_{CC}	−0.5~4.6	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~ 4.6 (Note 1)	V
		−0.5~ V_{CC} + 0.5 (Note 2)	
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	−20 (Note 3)	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	200	mW
Storage temperature	T_{stg}	−65~150	°C

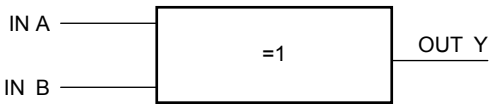
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0V

Note 2: High or Low State. I_{OUT} abusolute maximum rating must be observed.

Note 3: V_{OUT} < GND

IEC Logic Symbol



Truth Table

A	B	Y
L	L	L
L	H	H
H	L	H
H	H	L

Operating Ranges

Characteristics	Symbol	Value		Unit
Power supply voltage	V_{CC}	0.9~3.6		V
Input voltage	V_{IN}	0~5.5		V
Output voltage	V_{OUT}	0~3.6	(Note 4)	V
		0~V_{CC}	(Note 5)	
Output Current	I_{OH}/I_{OL}	±8.0	(Note 6)	mA
		±4.0	(Note 7)	
		±3.0	(Note 8)	
		±1.7	(Note 9)	
		±0.3	(Note 10)	
		±0.02	(Note 11)	
Operating temperature	T_{opr}	−40~85		°C
Input rise and fall time	dt/dV	0~10	(Note 12)	ns/V

Note 4: V_{CC} = 0V

Note 5: High or Low state.

Note 6: V_{CC} = 3.0~3.6 V

Note 7: V_{CC} = 2.3~2.7 V

Note 8: V_{CC} = 1.65~1.95 V

Note 9: V_{CC} = 1.4~1.6 V

Note 10: V_{CC} = 1.1~1.3 V

Note 11: V_{CC} = 0.9 V

Note 12: V_{IN} = 0.8~2.0 V, V_{CC} = 3.0 V

DC Electrical Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Typ.	Max	Ta = −40~85°C Min	Max	Unit
High-level input voltage	V_{IH}	—		0.9	V_{CC}	—	—	V_{CC}	—	V
				1.1~1.3	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
				1.4~1.6	V_{CC} × 0.65	—	—	V_{CC} × 0.65	—	
				1.65~1.95	V_{CC} × 0.65	—	—	V_{CC} × 0.65	—	
				2.3~2.7	1.7	—	—	1.7	—	
				3.0~3.6	2.0	—	—	2.0	—	
Low-level input voltage	V_{IL}	—		0.9	—	—	GND	—	GND	V
				1.1~1.3	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
				1.4~1.6	—	—	V_{CC} × 0.35	—	V_{CC} × 0.35	
				1.65~1.95	—	—	V_{CC} × 0.35	—	V_{CC} × 0.35	
				2.3~2.7	—	—	0.7		0.7	
				3.0~3.6	—	—	0.8		0.8	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −0.02 mA	0.9	0.75	—	—	0.75	—	V
			I_{OH} = −0.3 mA	1.1~1.3	V_{CC} × 0.75	—	—	V_{CC} × 0.75	—	
			I_{OH} = −1.7 mA	1.4~1.6	V_{CC} × 0.75	—	—	V_{CC} × 0.75	—	
			I_{OH} = −3.0 mA	1.65~1.95	V_{CC} -0.45	—	—	V_{CC} -0.45	—	
			I_{OH} = −4.0 mA	2.3~2.7	2.0	—	—	2.0	—	
			I_{OH} = −8.0 mA	3.0~3.6	2.48	—	—	2.48	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 0.02 mA	0.9	—	—	0.1	—	0.1	V
			I_{OL} = 0.3 mA	1.1~1.3	—	—	V_{CC} × 0.25	—	V_{CC} × 0.25	
			I_{OL} = 1.7 mA	1.4~1.6	—	—	V_{CC} × 0.25	—	V_{CC} × 0.25	
			I_{OL} = 3.0 mA	1.65~1.95	—	—	0.45	—	0.45	
			I_{OL} = 4.0 mA	2.3~2.7	—	—	0.4	—	0.4	
			I_{OL} = 8.0 mA	3.0~3.6	—	—	0.4	—	0.4	
Input leakage current	I_{IN}	V_{IN} = 0~5.5V		0~3.6	—	—	±0.1	—	±1.0	μA
Power off leakage current	I_{OFF}	V_{IN} = 0~5.5V V_{OUT} = 0~3.6V		0	—	—	1.0	—	10.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		3.6	—	—	1.0	—	10.0	μA

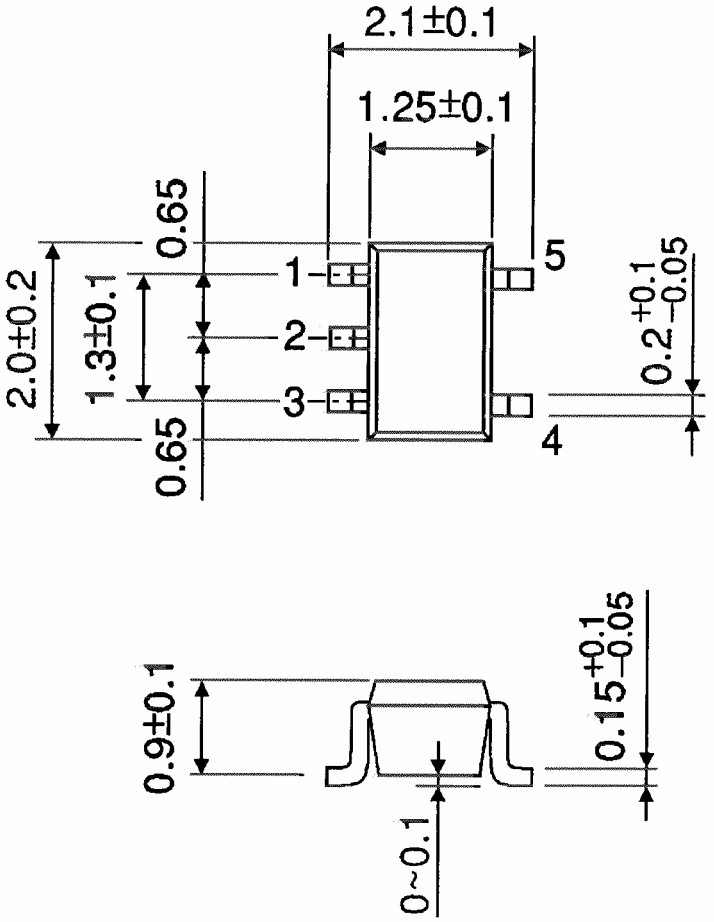
AC Electrical Characteristics (input $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{PLH} t_{PHL}	C_L = 10 pF, R_L = 1 MΩ	0.9	—	23.0	—	—	—	ns
			1.1~1.3	—	11.7	20.9	1.0	39.1	
			1.4~1.6	—	6.7	10.0	1.0	11.8	
			1.65~1.95	—	5.1	6.6	1.0	7.6	
			2.3~2.7	—	3.4	4.1	1.0	4.7	
			3.0~3.6	—	2.7	3.3	1.0	3.9	
		C_L = 15 pF, R_L = 1 MΩ	0.9	—	23.7	—	—	—	
			1.1~1.3	—	11.9	22.8	1.0	39.4	
			1.4~1.6	—	6.7	9.9	1.0	11.9	
			1.65~1.95	—	5.1	7.3	1.0	7.5	
			2.3~2.7	—	3.4	4.7	1.0	5.3	
			3.0~3.6	—	2.7	3.6	1.0	4.1	
		C_L = 30 pF, R_L = 1 MΩ	0.9	—	32.1	—	—	—	
			1.1~1.3	—	15.7	31.4	1.0	59.4	
			1.4~1.6	—	8.7	13.9	1.0	16.9	
			1.65~1.95	—	6.5	9.8	1.0	10.2	
			2.3~2.7	—	4.2	6.0	1.0	6.5	
			3.0~3.6	—	3.4	4.7	1.0	5.1	
Input capacitance	C_{IN}	—	3.6	—	3	—	—	—	pF
Power dissipation capacitance	C_{PD}	(Note 13)	0.9~3.6	—	9	—	—	—	pF

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:
$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Package Dimensions

SSOP5-P-0.65A Unit : mm



Weight: 0.006 g (typ.)

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20070701-EN GENERAL

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